

"DEVELOPMENT OF A ROUTINE METHOD FOR THE DETERMINATION OF MEAN CRYSTALLITE DIMENSIONS IN NUCLEAR MATERIALS BY X RAY DIFFRACTION LINE BROADENING AN APPLICATION EXAMPLE USING U308 MICROSPHERES

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ABSTRACT

A r while method for m an crystallite size datermination by X Ray diffraction fine broadening was established. Both step scanning and continuous scanning methods were extensively tested and the precision of the data obtained as a function of the crystallite size is discussed.

Emphasis is given to our contribution in order to eliminate instrumental effects as well as $K_{\Omega I}/K_{\Omega Z}$ doublet effect upon line broadening

Institumental correction was performed with a monocrystalline Si sample having mean crystallite size well above 13 000 Å Ichecked at our Laboratory) improving the accuracy of experimental data

 K_{22}/K_{Q2} doublet correction was handled with the aid of the modified Aschinger correction. The exact intensity relation between K_{Q2} and K_{Q1} peaks was determined instead of taking it for granted as 5

The mean crystallite dimension of U₃O₈ was calculated and the results show the dependence of this parameter on the quality of the microspheres

INTRODUCTION

Fission materials used in the form of coated particles have experienced great advances in the Gas Reactor Technology serving as basis for the development and progress of the HTGR concept⁽⁴⁾

One of the main advantages the use of fuels in the form of particles has brought is the possibility of achieving the highest burn ups reached so far, by incorporating moderators (as graphite) to the fuel Nowever, emphasis should be given to the fact that high efficiency of these fuels is primarily due to their structural properties.

As part of IEA's program, the CEQ (Chemical Engineering Division) has been developing a process for thicrospheres, production, and several batches of U₃O₈ and alumina microspheres have been prepared already.

As the microspheres production depends on several physicochemical parameters we focused our attention on one of them namely the mean dimension of the crystallites regions inside the solid where the unit cell repeats itself in an almost perfect fashion a quantity directly related to the feasibility of obtaining microspheres

The mean crystallite size is an important structural parameter not only where microspheres' production is concerned, but is also a meaningful structural parameter of any fuel material and it was the

purpose of our research to establish a fast and efficient method to datarmine it

FUNDAMENTALS

Scherrer⁽¹⁰⁾ first attempted to determine the influence of the crystallite size on X Ray diffraction peaks broadening and derived a methematical expression - assuming a cubic crystal structure -known today as the Scherrer equation

$$D = \frac{K \lambda}{\beta_{1/2} \cos \theta}$$
(1)

Assuming Scherrer's derivation was not general, Stokes and Wilson⁽¹¹⁾ derived an expression valid for any crystal structure. Employing a refined mathematical formalism as well as integrated intensities, these authors have nevertheless obtained an expression similar to Scherrer's, except for the value of <u>K</u> a shape constant. Scherrer equation holds for $K \approx 80$ whereas Stokes proposed K = 1.00. In practice, K is used as 90 because both works were carried on assuming the existence of only one crystallite actually one has an aggregate of them and therefore D is said to be mean crystallite size.

In expression (1) λ is the wavelength of the X Ray radiation $\underline{\theta}$ is the angle where maximum diffraction occurs and β 1/2 is the half-maximum peak breadth due only to the crystallite size of the material under investigation⁽³⁾

EXPERIMENTAL PROCEDURE

The experimental procedure may be divided into four main parts

- alignment of the diffractometer
- uniform sample preparation
- obtainment of diffraction profiles.
- deta correction

The elignment of the Rigsku SG 8 diffractometer is done according to its correspondent Rigaku manual⁽⁹⁾ and deserves have no further comments

Samples are prepared by pressing (27.5 ton/cm² during 3 minutes) in aluminum sample holders. As for the sake of compactness 5% cellulose may be added All samples are previously grinded in an agate morter, thus becoming homogeneous and practically strain free

Obtainment of a diffraction profile correspondent to a particular crystallographic (hkl) plane can be achieved by two alternative procedures

- conventional scanning where the sample is continually rotated around an appropriate Bragg angle, while the intensity is registered by a plotter on a chart. Profiles obtained this way are similar to the one shown in figure 1.
- step by step using a step scanning device where the intensity is measured at several angular positions equally spaced by small angle values, during a fixed time interval, say 20 seconds. The profiles are similar to the one given in figure 2.

In any case, the peak obtained has a certain helf-maximum breadth $\overline{B}_{1/2}$, which is a result of three major contributions

- crystallite mean dimension
- instrumental effect due to apparatus used

 $- K_{\alpha 1}/K_{\alpha 2}$ doublet overlap(*)

We are interested only in the effect due to crystallites and therefore we need the other two upon $B_{1/2}$

Effect (c) is easily eliminated using the Rachinger correction (appendix) yielding $\theta_{1/2}$ the half maximum peak breadth without the influence of $K_{\alpha 2}$

We are left with the problem of eliminating the instrumental effect to be able to calculate $\beta_{1/2}$. Theoretically this can be accomplished by applying expression (1) to a diffraction peak from any material possessing infinitely large crystallites as a consequence we would have $B \rightarrow 0$. Under these conditions the peak breadth would be due solely to instrumental effect.

However an ideal crystal (D $\rightarrow \infty$) is so far impossible to obtain. Many researchers have used as standard-crystals policrystalline materials having crystallites as large as possible. Anyhow they are soldom larger than 1 000 Å(B)

In the present work we adopted an original solution using a monocrystalline Si sample whose mean crystallite dimension is over 13 000Å(**) we were able to get diffraction peaks whose half maximum breadth b_{1/2} may well be considered as being due entirely to the particular apparatus used

It is known that the instrumental effect is a function of the Bragg angle i.e. $b_{1/2} = f(2|\theta|)$. This dependence is determined by obtaining diffraction peaks for several angular positions and plotting it thus constructing characteristic curves for each instrument (fig. 3). When investigating a given material (***) the instrumental effect at the angular positions where the peaks exist may be known by interpolation in the correspondent instrument curve.

The correction principle is as follows (12)

Figures 4a 4b and 4c represent respectively the sample diffraction peak ($K_{\alpha 1}/K_{\alpha 2}$ doublet effect already aliminated) the same diffraction peak if the diffractometer were ideal only crystallite size effect present and peak breadth due only to instrumental effect

The origins for g(z) and h(x) are chosen for convenience but at the same value of 2 θ . The relation between the three curves is obtained by considering the area g(z)dz on the curve for instrumental broadening the area g(z)dz is spread out by the function f(y) and at a displacement y the ordinate is the contribution dh(x) at the positron x = z + y on the h(x)-curve. Since the ordinates in the two curves are proportional to the peak areas

$$\frac{dh(x)}{f(y)} = \frac{g(z)dz}{A}$$

where A is the area of the f(y) curve.

With the replacement y = x - z, the ordinate of the h(x) curve is given by

$$h(\mathbf{x}) = \frac{1}{A} \int \mathbf{g}(\mathbf{z}) f(\mathbf{x} \ \mathbf{z}) d\mathbf{z}$$
(2)

⁽⁾ We are considering the material as strain free, although the actual profile is somewhat influenced by the existence of internal straway. In our case strain is negligible if not absolutely non existent.

As experimentally vehicled by using a diffraction apparatus having a highly collimated monochromator designed by and built by I E A 5 X Ray group (see ref. 2).

^(***) For each substance diffraction peaks occur at characteristic angular positions



Figure 1 - Strip chart record of the (001) peak of a U_3O_8 sample (Cu K_{01} radiation scanning speed $1/16^{\circ}/min)$



Figure 2 — Strip-chart record of the (001) peak of a U_3O_8 sample (Cu K_{α} rediation step scanning with step width 02° fixed time count 20 seconds)



Figure 3 - instrumental correction curves for diffractometers (i) and (ii)





_.__ .

B

Equation (2) indicates that the profile for the sample is a convolution of the functions representing particle size broadening and instrumental broadening. We measure the curves h(x) and g(z) and wish to obtain the particle-size broadening curve f(y). This is not convenient since f(y) is buried inside the convolution integral. By assuming shapes for the three curves, it is possible to use eq. (2) to obtain relations between the half maximum breadths of the curves.

Assuming the three curves are Gaussian, that is $w = Wexp \{\neg k | v^2 \}$ it is possible to show that

$$\beta_{\gamma_2}^2 = B_{\gamma_2}^2 - b_{\gamma_2}^2 \tag{3}$$

4 - APPLICATION OF THE METHOD

The method previously described was applied to finally grinded powder from $U_3 D_8$ microspheres. Figure 5 shows the diffraction profile of $U_3 O8$ for 20 between 10° and 110°

Seven samples were prepared and for each diffraction peaks were obtained using both diffractometers available at our Laboratory denoted by (I) and (II) (*)

The microspheres received for analysis have been previously size selected with 5 different standard sieves, with mesh dimensions varying between 0420 and 0053 cm

Samples numbered 1 to 5 belong to the same lot and samples numbered 6 and 7 to enother one obtained, under different conditions

Diffractometer I (Å)	Diffractometer II (Å)	Average (Å)
560 ± 28	575 ± 29	567 ± 29
592 ± 3 1	• 571 ± 29	581 ± 30
590 ± 31	599 ± 31	592 ± 31
591 ± 31	580 ± 30	587 ± 31
601 ± 31	590 ± 31	595 ± 31
377 ± 17	388 ± 17	382 ± 17
367 ± 16	375 ± 17	371 ± 17
	Diffractometer 1 (Å) 560 ± 28 592 ± 31 590 ± 31 591 ± 31 601 ± 31 377 ± 17 367 ± 16	Diffractometer IDiffractometer II $(Å)$ $(Å)$ 560 ± 28 575 ± 29 592 ± 31 571 ± 29 590 ± 31 599 ± 31 591 ± 31 580 ± 30 601 ± 31 590 ± 31 377 ± 17 388 ± 17 367 ± 16 375 ± 17

CONCLUSIONS

We have succeeded in establishing a fast and routinely applicable method for nuclear material control whenever structural parameters play an important role. The determination of the mean crystallite size by measuring Braggis diffraction peak breadth was computed using Scherrer equation, whose validity has been confirmed by several researchers (references 1.3.6,6.7) besides Scherrer himself⁽¹⁰⁾

^(*) The angular position for the U₃O₈ (001) diffraction peak is approximately $2\theta = 21.41^{\circ}$ and under this geometrical condition the instrumental effects for diffractometers (I) and (II) are $b_{13}^{I} = 106^{\circ}$ $b_{13}^{II} = -085^{\circ}$





Figure 6 - Per-cent error vs. crystallite size

(a) Step scanning fixed time count

(b) Conventional scanning scenning speed 1/16° min
 (c) Conventional scanning scenning speed 1/8° min

I



Figure 7 — Curve illustrating the principle of Rachinger correction. Contributions by K_{α_1} and K_{α_2} are show separately



Figure 8 - (333) Si reflexion. Cu K $_{lpha_1}$ and Cu K $_{lpha_2}$ peaks separated scanning speed 1/8 °/min

Our results were obtained with a precision not infarior to ones presented on the most outstanding previous works in this field like (1) thanks to the extremely satisfactory performance of the apparatus employed and the pioneer utilization of a standard crystal whose mean crystallite dimension was well over the ones used by other researchers

As our main objective was to apply the method in a rather routine fashion, we worked out curves in order to optimise the experimental procedure towards obtaining the highest precision within the time available (which in our Laboratory is invariably very scarce). In fig 6 curves show the percent error as a function of the crystallite size using three ways of obtaining the diffraction profile. Curve a corresponds to a step scanning fixed time count, curve b to a conventional scanning sample rotation speed 1/16°/min curve c to a conventional scanning sample rotation speed 1/8°/min

As the above method was developed using U₃O₈ microspheres fragmented as well as nonfragmented a few conclusions can be drawn concerning structural properties

- once we had samples of non-fragmented microspheres, the mean crystallite size was found to be 584 Å in average independent of the size of the microspheres analysed.
- within the same lot there is no evidence of drastic variations among crystallite sizes for any samples

This suggests that crystallite sizes are strongly dependent upon conditions under which microspheres are produced

In the future we plan to apply this method for microspheres formed under different physico-chemical process parameters such as temperature column holding time concentration of the chemicals employed etc. This will permit us to determine optimum production conditions in order to obtain UO₂ and U₃O₈ microspheres with the highest degree of structural perfection.

APPENDIX - The Rechinger Correction

Rechinger s correction is almed at the separation of the $K_{\alpha^{17}} \leq_{\alpha^2}$ doublet on diffraction peaks and is based on two assumptions

- 1- the peaks due to $K_{\alpha 1}$ and $K_{\alpha 2}$ are geometrically identical
- 2 the intensity of the peak due to K_{α^2} is one half of that due to K_{α^1}

Figure 7 illustrates one application of the method using a Si monocrystalline sample (111) reflexion considered. The dashed outer line is the peak obtained experimentally using unresolved Cu K_{α} radiation. The two internal curves were obtained using Rechinger's correction and represent the peaks due to $K_{\alpha'}$ and $K_{\alpha'}$ separately Δ is the angular separation between the peaks maxima m is a suitable number of intervals. Thus

$$l_1(\alpha_1) = l_1 - \Xi l_{1,m}(\alpha_1) \tag{A}$$

In expression (A) the numerical coefficient 5 is a consequence of assumption⁽²⁾ which does not prove being absolutely correct mainly because of the alignment of the diffractometer

In order to obtain a more precise value for the quotient $\frac{1}{1} \binom{\alpha_1}{\alpha_1}$ we obtained the Si (333) reflexion $\frac{1}{1} \binom{\alpha_1}{\alpha_1}$ where a complete separation of the peaks due to $K_{\alpha 1}$ and $K_{\alpha 2}$ is possible, their maximum heights occurring at $2\theta_{\alpha 1} = 94.96^{\circ}$ and $2\theta_{\alpha 2} = 95.27^{\circ}$ (fig. 8). Under these conditions we found

$$\frac{|(\alpha_2)|}{|(\alpha_1)|} = 45$$

When inserted in equation (A) we have

$$i_{1}(\alpha_{1}) = i_{1} - 45 i_{1} \frac{\alpha_{1}}{\alpha_{1}}$$
(B)

Expression (B) is a result of a careful use of the Rachinger correction, taking into account the type of apparatus employed and allowed us to resolve the $K_{\alpha 1}/K_{\alpha 2}$ doublet more precisely

In the case of fig 7 Δ = 08° and we chose m = 8 for convenience. Therefore

 $\begin{aligned} \mathbf{i}_{O}(\alpha_{1}) &= \mathbf{i}_{O}(\mathbf{i}_{1}(\alpha_{1}) = \mathbf{i}_{1}) & \mathbf{i}_{2}(\alpha_{1}) = \mathbf{i}_{2} \\ \mathbf{i}_{B}(\alpha_{1}) &= \mathbf{i}_{B} - 45 \mathbf{i}_{O}(\alpha_{1}) \\ \mathbf{i}_{B}(\alpha_{1}) &= \mathbf{i}_{B} - 45 \mathbf{i}_{1}(\alpha_{1}) \text{ and so an} \end{aligned}$

The origin is also chosen for convenience, at the left hand side and the accuracy is satisfactory from this point to about half way down on the right hand side when fluctuations may occur, the right tail of the curve is graphically completed having in mind the fact it is symmetrical to the left tail.

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RÉŞUMÉ

كم• méthode de routure a été établie pour la détermination de le taille moyenne des cristellites per élargissement de la lighé de diffraction des reyons X. Les méthodes de belevege per étages éussiblen que celles de belevege continue ant été plusieurs fois testées, et le précision des donnés obtenus en fonction de la taille des cristellites à été traitée

On met en relief notre contribution dans le buz d'éliminer l'effet instrumental aussi bien que l'effet du au doublet K₀₁ /K_{m2} dans l'élargissement de la ligne

La correction instrumentalle a été effectué en employant un monocristel de Si avac une taille moyanne de cristallites au-dessur de 13.000 Å (donnée confittuée a notre Laboratoire) améliorant la précision des données expérimentales

Le correction des doublets K₀₁/K₀₂ à été efféctué par correction de Aschinger, modifiée. On a tenu compte de la relation axecte entre les intansités a K₀₁/K₀₀ au lieu de dire que clest égal a 15

La dimension moyenne des cristalités a été calculée, et les résultats montrent la dépendance de ce paramètre par rapport a la qualité des microsphères

RESUMO

Um método de rotine para a determinação do tamanho médio dos cristelitos por elargamento da linha de difração dos raios X foi estabelecido. Tanto os métodos por variedura passo e passo quento por veriedura contínua foram exaustrivamente testados e a precisão dos dados obtidos em função do tamanho dos cristalitos á discutido.

Destacem se nosse contribuição original no sentido de stiminar o efeito instrumente) bem como o efeito devido eo dubleto K_{Q1} /K_{Q2} no stergemento de linhe

A correção instrumental foi sfatuada com o uso de um monocristal de Si qua tam um tamanho médio dos

14

cristalitos acima de 13000 Å (dado esta confirmado em nosso laboratório i melhorando a precisão dos dados experimentais

A correção dos dubletos K_{Q1} /K_{Q2} foi aterivado por meio da correção de Rachinger modificada. A relação exate entre as intensidades dos picos devidos e ^ωαι /K_{Q2} foi levado em col·la aplinivés de se adotá la igual al 5

A dimensão média dos criste itos foi calculada e os resultados mostram a dependencia deste parametro com a qual-dade das microesteras

REFERENCES

- 1 ALEXANDER L. The synthesis of x ray spectrometer line profiles with application to crystallite size measurements J appl Phys. Lancaster Pa. 25(2) 155.61.1954
- 2 IMAKUMA K Difração multipla de raios x em monocristais de LIF irradiados São Paulo 1972. (Ph D Thesis)
- 3 KLUG H P & ALEXANDER L E X ray diffraction procedure. New York Wiley 1954
- 4 KRAWCZYNSKI S HTR fuel technology and irradiation testing seminar held in Autumn 1973 São Paulo Instituto de Energia Atomica 1973
- 5 LAUE M yon Z Krist <u>64</u>115 (1926) apud KLUG H P & ALEXANDER L E X ray diffraction procedures New York Wiley 1954 g 491
- 6 MURDOCK C L C The resolving power of an octahedral crystal for x rays Phys Rev Minneapolis. Minn 2 ser <u>31</u> 304, 1928.
- 7 PATTERSON A L The determination of the size and shape of crystal particles by x rays Phys Rev. Minneapolits Minn. 2 ser. <u>49</u>.884, 1936.
- 8 RAU R C Routine crystallite size determination by x ray diffraction line broadening Adv X ray Analysis New York <u>5</u> 104 16 1961
- 9 RIGAKU CORPORATION Tokyo Instruction manual n ME210 AJ2 in tin
- 10 SCHERRER P Gottinger Nachrichten 2,08 (1918) apud KLUG H P & ALEXANDER L E X ray diffraction procedures New York Wiley 1954 p 491
- 11 STOKES A R & WILSON A J C A method of calculating the integral breadths of Debye Schemer lines Proc Cemb phil Soc London 38 313 22 1942
- ¹² WARREN B E X ray diffraction Reading Mass Addison Wesley 1968.